Building blocks of zeolites on an aluminosilicate ultra-thin film

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1. Introduction

The structure of an aluminosilicate film composed of a single layer of polygonal prisms, determined with atomic resolution, is analyzed in this work, revealing the presence of some of the most frequently found building blocks of zeolites. These include units that have been repeatedly proposed as precursors for the formation of these crystalline porous materials [1]. The structure of zeolites and zeolite-related architectures is of great importance as it is intrinsically related to the many applications of these materials. In terms of the chemistry of these systems, it has been shown that small variations in structural parameters near the active sites can have a significant effect on their catalytic activity [2]. In addition, there is substantial interest from a fundamental point of view, as they provide a fascinating subject of study for the field of topology. This is reflected in the millions of hypothetical zeolite structures that have been proposed just on topological basis [3], in addition to the 201 structures existent as of August 2012 [4]. Additionally, resolving the structure at the atomic level can lead to a better understating of the mechanism by which the frameworks are assembled, which is currently a topic under active debate [1,5].

We recently reported the successful preparation a two-dimensional model system for zeolites which can be studied by scanning probe techniques to that level of detail and under very controlled conditions in an ultra-high vacuum environment [6].

Zeolites are crystalline materials composed of a network of tetrahedra, where the center of the tetrahedron is an atom T (Si or Al) which is linked to four other T-atoms by an oxygen bridge. The tetrahedron TO₄ is known as the primary building unit. These tetrahedra, where the center of the tetrahedron is an atom T (Si or Al) which is linked to four other T-atoms by an oxygen bridge. The tetrahedron TO₄ is known as the primary building unit. These tetrahedra, where the center of the tetrahedron is an atom T (Si or Al) which is linked to four other T-atoms by an oxygen bridge. The tetrahedron TO₄ is known as the primary building unit. These tetrahedra, where the center of the tetrahedron is an atom T (Si or Al) which is linked to four other T-atoms by an oxygen bridge. The tetrahedron TO₄ is known as the primary building unit. These tetrahedra, where the center of the tetrahedron is an atom T (Si or Al) which is linked to four other T-atoms by an oxygen bridge. 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These building blocks appear 25 (d7r), 17 (d8r) and 5 (d6r) times, in the set of 176 unique zeolite frameworks reported up to 2007. In addition, larger ensembles of rings observed in this system can be related to more complex ensembles in zeolites, such as the α-cage in zeolite A. The structures were here identified by a combination of scanning tunneling microscopy, low energy electron diffraction, infrared reflection absorption spectroscopy, X-ray photoelectron spectroscopy and X-ray absorption spectroscopy experiments.

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the transformation of Ba2+ substituted zeolite A (framework type three-dimensional zeolite structures. A clear example of this is consisting of a crucible containing metallic Al. Effects. Aluminum was evaporated from a home-built evaporator of ions toward the sample, which could create uncontrolled de-
from Goodfellow) was deposited using an e-beam-assisted evapo-
and scanning tunneling microscopy (STM). Silicon (99.99% purity, copy (XPS), infrared reflection absorption spectroscopy (IRAS), energy electron diffraction (LEED), X-ray photoelectron spectros-
Mateck) surface was cleaned with cycles of Ar+ sputtering (2 kV, of 4-membered rings[7].
A close relation exists between layered aluminosilicates and three-dimensional zeolite structures. A clear example of this is the transformation of Ba2+ substituted zeolite A (framework type LTA) into the layered barium aluminosilicate known as hexacelsian upon thermal treatment [9]. This layered aluminosilicate was first described by Yoshiki in 1951 [10] and each layer has the same connect-
cause the crystal to be successfully used as a model system for zeolites, from the chemistry point of view, by generating highly acidic bridging hydroxyls at high Al contents [6]. The structure of this system shows striking similarities with different zeolites and shows features that are absent in analogous pure-silica cases. Due to the high importance of zeolites, the structural features of the aforementioned system deserve a detailed description and analysis and this is explored in the present work.

2. Experimental

2.1. Experimental setup

The preparation and the experiments reported here were performed in an ultrahigh-vacuum (UHV) system (base pressure be-
low 5 × 10⁻10 mbar) counting with the following techniques: low energy electron diffraction (LEED), X-ray photoelectron spectroscopy (XPS), infrared reflection absorption spectroscopy (IRAS), and scanning tunneling microscopy (STM). Silicon (99.99% purity, from Goodfellow) was deposited using an e-beam-assisted evapo-
ator (Focus EFM3). During evaporation, the substrate was biased at the same potential as the Si rod (1000 V) to prevent acceleration of ions toward the sample, which could create uncontrolled de-
fects. Aluminum was evaporated from a home-built evaporator consisting of a crucible containing metallic Al.

2.2. Sample preparation

A Ru(0001) (8 mm in diameter and 1.5 mm in thickness, from Mateck) surface was cleaned with cycles of Ar⁺ sputtering (2 kV, 15 μA) and annealing to ~1200 °C. The clean surface was then pre-covered with a 30-(2 × 2) overlayer by exposing to 3 × 10⁻⁶ mbar O₂ at 950 °C. The aluminosilicate film was prepared by subsequently depositing ~0.64 ML (1 ML = 1.57 × 10¹⁵ atoms/cm²) of Si and ~0.36 ML of Al on the 30-(2 × 2)/Ru(0001) surface under an O₂ pressure of 2 × 10⁻⁷ mbar. The film was then oxidized by exposing it to a pressure of O₂ of 3 × 10⁻⁶ mbar while heating the sample up to ~950 °C, keeping it at this temperature for 10 min and then slowly cooling it down always under O₂ ambient.

2.3. Imaging conditions and image corrections

STM images were acquired with and Omicron ST Microscope at 300 K in the constant-current mode, with a current set-point of ~86 pA and bias voltage of ~1 V applied to the sample. All images were filtered to reduce noise. Images shown in Figs. 5 and 6 were corrected to account for thermal drifts during the acquisition.

3. Results and discussion

The aluminum and silicon contents were determined by XPS of the Al2s and Si2p core levels. A correction factor of 1.17 was applied to the ratio of the peak areas Al2s/Si2p to account for the differ-
ent sensitivity factors of these two levels, based on experimental data obtained for an electron analyzer similar to the one used in our experiments [12]. This yielded a molar ratio Al/Si = 0.56. (XPS spectra shown in the Supporting information). The different motifs found in this structure can be clearly identified with high-resolu-
tion by STM. Although bulk zeolites are insulators, the film re-
ported here is thin enough to allow tunneling from the scanning tip to the substrate. [13] Fig. 2 shows an STM image containing a variety of distinct features. Similar to the case of an ordered pure-silica bilayer system reported previously [11], the majority of the framework is composed of double 6-membered rings (d6r). In the case of the ordered silica film, [11] as well as a vitreous one reported recently, [14] bright protrusions arranged as triangles were assigned to the position of the top-most oxygen atoms in the film, where these three O atoms are bound to the same tetrahedral atom. The proposed model was supported as well by density func-
tional theory calculations. Although only the immediate surface can be seen in the image, evidence of the same structure repeating symmetrically below is given by IRAS [6]. The infrared spectrum for this system, showing sharp phonon vibration peaks at 1277 and 702 cm⁻¹ is shown in Fig. 3. The phonon modes assigned to these high- and low-frequencies are shown schematically as insets. The 1277 cm⁻¹ peak is significantly lower in frequency than the one on the pure silica film (1300 cm⁻¹). We have assigned this effect to the incorporation inhomogeneities (Al atoms) in this crystal-
talline lattice, disrupting the phonon vibration and thus lowering the frequency. [6] Nevertheless, the spectrum clearly indicates that the same structure that is observed by STM in the top layer is re-
peted in the bottom layer and that the two layers are linked by T–O–T bridges, as shown in the insets, similar to the case reported by Löffler et al. [11] More detailed studies of the silica system were performed later in terms of electronic structure, [15] growth mode, [16] and influence of the substrate where the film is grown. [17] The inset at the upper-left corner of Fig. 2 shows the LEED pattern of this film, taken at a beam energy of 60 eV, where spots corre-
sponding to a (2 × 2) structure, with respect to the Ru(0001) underlying lattice, are observed. In addition to the d6r, direct space imaging by STM (Fig. 2) shows the presence of other structures lacking long-range order, and thus not visible by LEED. As expected from the LEED pattern, the most abundant structure is the d6r. Close-ups of 1.5 × 1.5 nm sections of the large scale image showing double N-membered rings are shown in insets a (d6r), b (d6r and
A significant portion of the surface is composed of ordered regions containing only 6-membered rings. These regions were found to account for ~53% of the surface. The number of rings for each size was counted in a set of images obtained for this aluminosilicate surface with good-enough resolution to clearly distinguish the position of the tetrahedral atoms in most cases. Note that since what the images show is an arrangement of polygons filling the plane, a simple way to determine the polygon size with a high degree of certainty is to take advantage of the fact that polygons share their edges with the neighboring ones and thus their size is equal to the number of surrounding rings. A collage of the images used for counting is included in the Supporting information. The size could be clearly identified for 526 rings, out of which 279 were 6-MR located in ordered regions. The ring statistics, excluding the 6-membered rings within the aforementioned ordered regions, are shown in Fig. 4 as a histogram for ring sizes between 4 and 11. Note that 6-MR (and small clusters of 6-MR) within the regions lacking long-range order are included in the histogram. For comparison, the normalized ring distribution for the vitreous silica reported by Lichtenstein et al. is also included (bars with dashed-line borders) [14].
This leads to the formation of Al–O–Si moieties which re-

Fig. 5. (a) Region with a chain of alternating 4- and 8-membered rings. (b) Schematic representation of this region including 6-membered rings adjacent to the chain. 8-MRs are shown in green, 6-MRs in orange and 4-MRs in blue. (c) Three-
dimensional representation including the identical layer repeated below. (d) Arbitrary cutout from (c). (e) Unfolded version of the cutout in (d); (f) α-Cage. This is a CBUs of Zeolite A, and can be obtained by folding the structure shown in (e). (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

The white arrow indicates the direction of the shift. The white dashed line is a guide to the eye to visualize the shift. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

Fig. 6. (a) Domain boundary with rings emphasized by dashed line. (b) Boundary rings colored according to size in order to ease the visualization of the boundary structure. The white arrow indicates the direction of the shift. The white dashed line is a guide to the eye to visualize the shift. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

the same structures that are observed by STM are repeated be-

neath with O atoms bridging the two layers through T–O–T link-

ages, we will next proceed to analyze the distribution of rings on

the rest of the surface, i.e.: the regions lacking long range order.

A striking feature of this system is the fact that in most cases 5-

membered rings (5-MR) are located next to 7-MR, while 4-MR

are located next to 8-MR (or larger rings). The case of adjacent 5-

and 7-MR can be related to Stone–Wales defects which are well-

known in hexagonal networks of carbon-based materials [18],

and such motifs have also been shown for the case of a two-dimen-

sional vitreous silica network [14]. The latter system consisted of

non-ordered arrangements of double N-membered rings with N

ranging from 4 to 9, with asymmetric ring size distributions peak-

ing at d6r and having d5r as the second most abundant species [14]. However, for the case reported here, in which aluminum atoms have been incorporated into the framework, there is a sig-

nificant increase in the population of d4r and d8r, such that the

number of instances is comparable to the number of d5r, d7r. A sil-

ica bilayer film grown on graphene, with vitreous regions similar to

the ones reported by Lichtenstein, was reported by Huang et al., in

which case an even lower population was found for d4r [19]. While

d5r and d7r have been found on pure silica systems, these motifs,

although present in many zeolites, do not comprise any of the 23

SBUs. In fact, zeolites show a strong preference for ring sizes hav-

ing even numbers of tetrahedral atoms, and that is related to

Lowenstein’s rule [20], which states that Al–O–Al moieties are for-

bidden. This leads to the formation of Al–O–Si moieties which re-

peat around the rings, resulting in the observed even-numbered

rings. For the limit case of a 1:1 Si:Al ratio, all rings must be

even-numbered. This trend showing a preference of even-num-

bered rings in zeolites was noted already in early works [21]. Fur-

thermore, the d4r and the d8r units were then proposed to be

present in the “crystallizing magma” in one of the first references

to the synthesis mechanism in 1959 by Barrer et al. [21]. Although

STM images allow the determination of the position of tetrahedral

atoms, the distinction between Al and Si atoms is not clear. Nev-

ertheless, based on the previous discussion, the increase in the num-

ber of d4r and d8r can be clearly attributed to the incorporation of

Al atoms to the framework.

In the case of d4r units, there is a fourfold increase for the al-

uminosilicate compared to the vitreous silica. A high population

of cubes (d4r) has been previously related to the introduction of

atoms that allow smaller T–O–T angles into silica networks [22].

For the case pure silica there is a preferential formation of hexag-

onal networks for the crystalline bilayer structure. For films that do

not reach the crystalline state, such as the one reported by Lichten-

stein et al., there is also a significant population of 5- and 7-MRs,

since these are the ones with the smaller deviation from the tetra-

hedral angles, after the 6-MR. From the three main structural

parameters, T–O–T angle, O–T–O angle and T–O bond length, the

T–O–T angle is the one that contributes the most to framework

flexibility with values ranging usually between 140° and 165°,

although values as low as 130° and as high as 180° have been re-

ported [22,23]. The introduction of atoms with a less covalent T–O

bond, such as Al, Ge or Ga, result in more flexible networks in

terms of the O–T–O angle, and this is clearly the case for this sys-

tem reported here. While for the case of SiO4 the units the O–Si–O

angle is rigid and close to the ideal value of 109° 28’, the AlO4 tet-

rahedra can undergo distortions with a lower energetic penalty,

[23] and O–Al–O angles between 105° and 120° have been found

for the extreme case of aluminosodalites. [24] In terms of T–O

bond lengths, typical values for Si–O, Al–O, Ge–O and Ga–O are

1.58–1.64, 1.70–1.73, 1.73–1.76 and 1.84–1.92 Å, respectively. [22]

Based on the discussion in previous paragraphs, it can be safely

assumed that Al–O–Si–O–Al linkages are present in the d4r. The

stability of such arrangements was in fact clearly described by

the Sauer group, even for low Al contents [25]. They showed, by

means of first-principles calculations, that for pure silica frame-

works the hexagonal prism structure (d6r) is more stable than

the cube one (d4r) [26], while the stability order is reversed for

the Al-substituted case [27], i.e. the cube structure (d4r) is more

stable for aluminosilicates.

A motif with alternating d4r and d8r was often observed when

scanning this system (shaded areas with white dashed lines in

Fig. 2). Fig. 5a shows one of the regions with 4 times the alternating $d^4r$ and $d^8r$ motif. What follows is a topological exercise with this structure that allows us to relate it to the previously referred transformation between the widely used synthetic zeolite A (framework type LTA) and the layered material hexacelsian, with a structure very similar to our film [9]. A CBU of LTA is the $\alpha$-cage, which is shown in Fig. 5f (note that the $\alpha$-cage is not only found in LTA but it has been found in 7 other framework types) [7]. A label showing the number of tetrahedral atoms forming the rings is shown in the image in Fig. 5a, and a dot-bar representation of the connectivity of the T atoms is shown in Fig. 5b. Since the same structural motif is repeated below for this system, the bottom layer and the connection to the top layer are shown in Fig. 5c. Let us now consider a cut-out of a section of this structure (Fig. 5d) and unfold that section such that it becomes now planar as shown in Fig. 5e. Strikingly, this planar arrangement of rings, which was contained within our structure, can now be folded into an $\alpha$-cage. This remarkable fact, that the same set of rings with the same connective sequence between rings is shared between this planar framework, and the $\alpha$-cage, provides a strong indication about the mechanism by which three-dimensional zeolites can be transformed into planar structures by simple thermal treatments [9]. It is possible that after the unfolding of the $\alpha$-cage unit into a planar structure upon heating, the resulting alternating sequence of $d^4r$ and $d^8r$ could then be converted into the $d^4r$ units of hexacelsian, following a mechanism analogous to the inverse of the formation of Stone-Wales-like defects. Further studies in this regard could be provided by theory, although this is beyond the scope of this work.

The alternating 4- and 8-MR structure also serves as a boundary that shifts adjacent crystalline regions by one unit cell of the Ru(0001) substrate in the direction normal to the chains of 4- and 8-MR. Fig. 6 shows a clear example of this. There, two crystalline domains can be observed, separated by two different kinds of domain boundaries. One of them is the previously referred one (4-MR + 8-MR)$_n$, while the second one consists of alternating pairs 7- and 5-MRs. However, the latter domain boundary runs only 30° off the direction of the shift. The two crystalline domains are shifted by one Ru(0001) unit cell. The white arrow indicates the direction of the shift while the white dashed-line is a guide to the eye to ease the visualization of the shift. For comparison, domain boundaries containing 5- and 7-MR have also been observed for crystalline silica bilayer systems (unpublished data). In addition, for the silica bilayer, we have found domains shifted by slightly more than one substrate unit cell, running perpendicular to the direction of the shift, in an analogous manner to the (4-MR + 8-MR)$_n$ domain boundary. However, for the silica case, these domain boundaries did not have 4-MRs but consisted of alternating 8-MRs and pairs of 5-MRs. Note also that these (8-MR + 2 \times 5-MR)$_n$ boundaries run along the main Ru(0001) directions, while for the aluminosilicate they are 30° off (unpublished data). It is clear from analyzing both crystalline and vitreous regions of this film that the incorporation of Al results in changes in the rings-size distribution favoring the presence of even-numbered rings and especially 4-MR.

4. Conclusions

In summary, polygonal prisms of tetrahedral atoms, which constitute the building blocks of significant number of zeolites, were identified with atomic resolution in a flat aluminosilicate. A substantial increase is observed in the population of prisms with even-numbered rings, when compared to analogous pure-silica systems. These units had been previously proposed as precursors for the zeolite formation. In particular, the number of double four-membered rings (cubes) shows a significant increase. In addition, close topological relations between this planar aluminosilicate and zeolite A were shown, which can lead to explanations of the mechanisms of transformations between these systems.

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Appendix A. Supplementary data

Supplementary data associated with this article can be found in the online version, at http://dx.doi.org/10.1016/j.jmicromeso.2012.08.014.

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